

November 2009

# **FAN4931** Ultra-Low Cost, Rail-to-Rail I/O, CMOS Amplifier

### **Features**

- 200µA Supply Current per Amplifier
- 3.7MHz Bandwidth
- Output Swing to within 10mV of Either Rail
- Input Voltage Range Exceeds the Rails
- 3V/µs Slew Rate
- 25nV/√Hz Input Voltage Noise
- FAN4931 Competes with LMV931; Available in SC70-5 Package
- Fully Specified at +2.7V and +5V Supplies

## **Applications**

- Portable / Battery-Powered Applications
- PCMCIA, USB
- Mobile Communications, Cellular Phones, Pagers
- Notebooks and PDAs
- Sensor Interface
- A/D Buffer
- Active Filters
- Signal Conditioning
- Portable Test Instruments

## **Description**

FAN4931 is an ultra-low cost voltage feedback amplifier with CMOS inputs that consumes only 200µA of supply current, while providing ±33mA of output short-circuit current. This amplifier is designed to operate from 2.5V to 5V supplies. The common-mode voltage range extends beyond the negative and positive rails.

The FAN4931 is designed on a CMOS process and provides 3.7MHz of bandwidth and 3V/µs of slew rate at a supply voltage of 5V. The combination of low power, rail-to-rail performance, low-voltage operation, and tiny package options make this amplifier well suited for use in general-purpose and battery-powered applications.

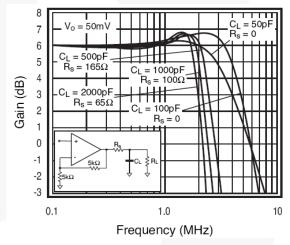


Figure 1. Frequency vs. Gain

# **Ordering Information**

Part Number	Operating Temperature Range	Package	<b>©</b> Eco Status	Packing Method
FAN4931IP5X	-40 to +85°C	5-Lead SC70 Package	Green	Tape and Reel (3000)

For Fairchild's definition of Eco Status, please visit: <a href="http://www.fairchildsemi.com/company/green/rohs\_green.html">http://www.fairchildsemi.com/company/green/rohs\_green.html</a>.

# **Typical Application**

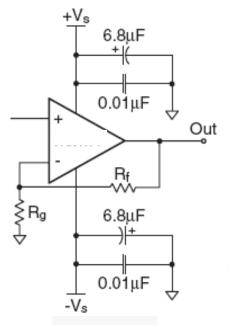


Figure 2. Typical Application

# **Pin Configurations**

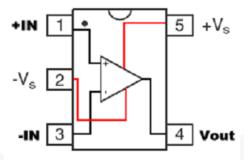


Figure 3. Pin Assignments

# **Pin Assignments**

Pin#	Name	Description
1	+IN	Positive Input
2	-Vs	Negative Supply
3	-IN	Negative Input
4	$V_{OUT}$	Output
5	+V <sub>S</sub>	Positive Supply

## **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Functional operation under any of these conditions is NOT implied. Performance and reliability are guaranteed only if operating conditions are not exceeded.

Symbol	Parameter			Max.	Unit
Vcc	Supply Voltage			6	V
$V_{IN}$	Input Voltage Range			+V <sub>S</sub> +0.5	V
TJ	Junction Temperature		+150	°C	
T <sub>STG</sub>	Storage Temperature			+150	°C
TL	Lead Soldering, 10 Seconds			+300	°C
$\Theta_{JA}$	Thermal Resistance <sup>(1)</sup>			331	°C/W
ESD	Flootrootatic Discharge Conshility	Human Body Model, JESD22-A114		5	kV
EOD	Electrostatic Discharge Capability	Charged Device Model, JESD22-C101		2	ĸV

#### Note:

1. Package thermal resistance JEDEC standard, multi-layer test boards, still air.

## **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
+Vs	Supply Voltage		5.25	V
T <sub>A</sub>	Operating Temperature Range	-40	+85	°C

# **Electrical Specifications at +2.7V**

 $V_S \!\!=\! +2.7 V,~G \!\!=\! 2,~R_L \!\!=\! 10 k\Omega$  to  $V_S \!/\! 2,~R_F \!\!=\! 5 k\Omega;$  unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
Frequency Do	omain Response	1		•		
UGBW	2dD Dog dwidth	G=+1		4		MHz
BW <sub>SS</sub>	-3dB Bandwidth			2.5		MHz
GBWP	Gain Bandwidth Product			4		MHz
Time Domain	Response					
t <sub>R</sub> , f <sub>F</sub>	Rise and Fall Time	Vo=1.0V Step		300		ns
OS	Overshoot	V <sub>O</sub> =1.0V Step		5		%
SR	Slew Rate	Vo=3V Step, G=-1		3		V/µs
Distortion and	d Noise Response					•
HD2	2nd Harmonic Distortion	V <sub>O</sub> =1V <sub>PP</sub> , 10kHz		-66		dBc
HD3	3rd Harmonic Distortion	V <sub>O</sub> =1V <sub>PP</sub> , 10kHz		-67		dBc
THD	Total Harmonic Distortion	V <sub>O</sub> =1V <sub>PP</sub> , 10kHz		0.1		%
e <sub>n</sub>	Input Voltage Noise			26		nV/√Hz
DC Performa	nce					
V <sub>IO</sub>	Input Offset Voltage <sup>(2)</sup>		-6	0	+6	mV
dV <sub>IO</sub>	Average Drift			2.1		μV/°C
I <sub>bn</sub>	Input Bias Current			5		pA
PSRR	Power Supply Rejection Ratio <sup>(2)</sup>	DC	50	73		dB
A <sub>OL</sub>	Open-Loop Gain	DC		98		dB
Is	Supply Current per Amplifier <sup>(2)</sup>			200	300	μA
Input Charact	teristics					
R <sub>IN</sub>	Input Resistance			10		GΩ
C <sub>IN</sub>	Input Capacitance			1.4		pF
CMIR	Input Common Mode Voltage Range			-0.3 to 2.6		V
CMRR	Common Mode Rejection Ratio <sup>(2)</sup>	DC, V <sub>CM</sub> =OV to 2.2V	50	65		dB
Output Chara	cteristics			•		
V	Outrot Valtage Suine (2)	$R_L$ =10k $\Omega$ to $V_S$ /2	0.03	0.01 to 2.69	2.65	
Vo	Output Voltage Swing <sup>(2)</sup>	$R_L$ =1k $\Omega$ to $V_S$ /2		0.05 to 2.55		V
I <sub>SC</sub>	Short-Circuit Output Current			+34/-12		mA
Vs	Power Supply Operating Range			2.5 to 5.5		V

### Note:

2. 100% tested at  $T_A$ =25°C.

# **Electrical Specifications at +5V**

 $V_S \!\!=\! +5V,~G \!\!=\! 2,~R_L \!\!=\! 10k\Omega$  to  $V_S/2,~R_F \!\!=\! 5k\Omega;$  unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
Frequency Do	omain Response			-1		
UGBW	0.4D D = 1.4.4.44.	G=+1		3.7		MHz
BW <sub>SS</sub>	-3dB Bandwidth			2.3		MHz
GBWP	Gain Bandwidth Product			3.7		MHz
Time Domain	Response		•	•		•
t <sub>R</sub> , f <sub>F</sub>	Rise and Fall Time	V <sub>O</sub> =1.0V Step		300		ns
OS	Overshoot	V <sub>O</sub> =1.0V Step		5		%
SR	Slew Rate	V <sub>O</sub> =3V Step, G=-1		3		V/µs
Distortion and	Noise Response					•
HD2	2nd Harmonic Distortion	V <sub>O</sub> =1V <sub>PP</sub> , 10kHz		-80		dBc
HD3	3rd Harmonic Distortion	V <sub>O</sub> =1V <sub>PP</sub> , 10kHz		-80		dBc
THD	Total Harmonic Distortion	V <sub>O</sub> =1V <sub>PP</sub> , 10kHz		0.02		%
en	Input Voltage Noise			25		nV/√Hz
DC Performan	ice					
V <sub>IO</sub>	Input Offset Voltage <sup>(3)</sup>		-8	0	+8	mV
dV <sub>IO</sub>	Average Drift			2.9		μV/°C
I <sub>bn</sub>	Input Bias Current			5		pA
PSRR	Power Supply Rejection Ratio <sup>(3)</sup>	DC	50	73		dB
A <sub>OL</sub>	Open-Loop Gain	DC		102		dB
Is	Supply Current per Amplifier <sup>(3)</sup>			200	300	μA
Input Charact	eristics					
R <sub>IN</sub>	Input Resistance			10		GΩ
C <sub>IN</sub>	Input Capacitance			1.2		pF
CMIR	Input Common Mode Voltage Range	Typical		-0.3 to 5.3		V
CMRR	Common Mode Rejection Ratio <sup>(3)</sup>	DC, V <sub>CM</sub> =0V to V <sub>S</sub>	58	73		dB
Output Chara	cteristics					
\/	Output Voltage Swing <sup>(3)</sup>	$R_L$ =10k $\Omega$ to $V_S$ /2	0.03	0.01 to 4.99	4.95	V
Vo	Output voltage Swing	$R_L$ =1k $\Omega$ to $V_S/2$		0.1 to 4.9		v
I <sub>SC</sub>	Short-Circuit Output Current			±33		mA
Vs	Power Supply Operating Range			2.5 to 5.5		V

### Note:

3. 100% tested at  $T_A$ =25°C.

## **Typical Performance Characteristics**

 $V_S$ =+2.7, G=2,  $R_L$ =10k $\Omega$  to  $V_S$ /2,  $R_F$ =5k $\Omega$ ; unless otherwise noted.

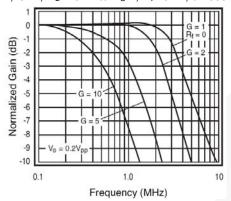


Figure 4. Non-Inverting Frequency Response (+5)

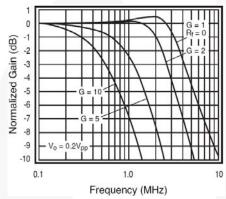


Figure 6. Non-Inverting Frequency Response

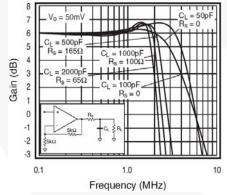


Figure 8. Frequency Response vs. C<sub>L</sub>

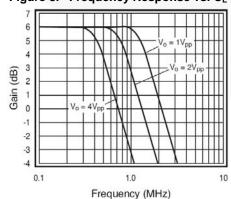


Figure 10. Large Signal Frequency Response (+5V)

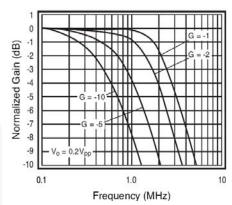


Figure 5. Inverting Frequency Response (+5V)

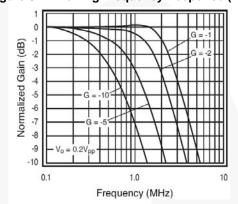


Figure 7. Inverting Frequency Response

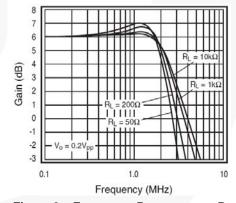


Figure 9. Frequency Response vs. R<sub>L</sub>

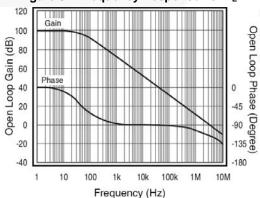


Figure 11. Open-Loop Gain and Phase vs. Frequency

## **Typical Performance Characteristic**

 $V_S$ =+2.7, G=2,  $R_L$ =10k $\Omega$  to  $V_S$ /2,  $R_F$ =5k $\Omega$ ; unless otherwise noted.

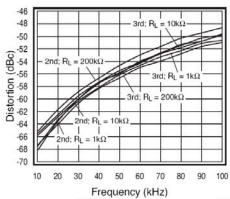


Figure 12. 2nd and 3rd Harmonic Distortion

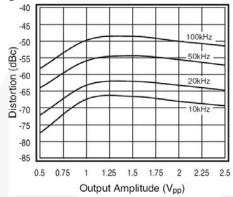


Figure 14. 3rd Harmonic Distortion vs. Vo

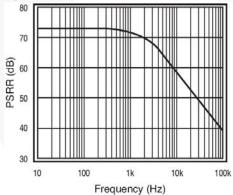


Figure 16. PSRR V<sub>S</sub>=5V

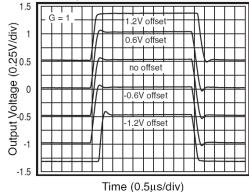


Figure 18. Pulse Response vs. Common-Mode Voltage

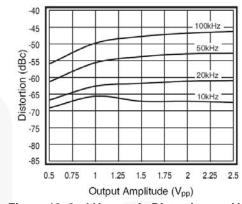


Figure 13. 2nd Harmonic Distortion vs. Vo

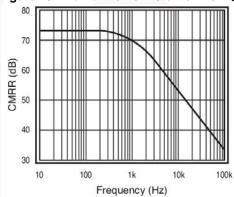


Figure 15. CMRR V<sub>S</sub>=5V

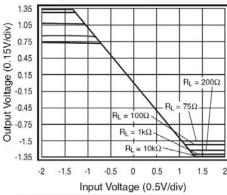


Figure 17. Output Swing vs. Load

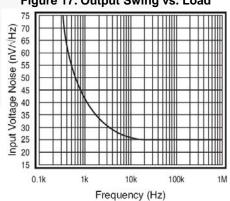


Figure 19. Input Voltage Noise

## **Application Information**

### **General Description**

The FAN4931 amplifier is a single-supply, general-purpose, voltage-feedback amplifier, fabricated on a bi-CMOS process. It features a rail-to-rail input and output and is unity gain stable. The typical non-inverting circuit schematic is shown in Figure 20.

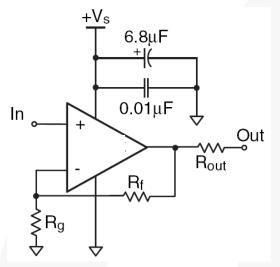


Figure 20. Typical Non-Inverting Configuration

### **Input Common-Mode Voltage**

The common-mode input range extends to 300mV below ground and to 100mV above  $V_{\rm S}$  in single-supply operation. Exceeding these values does not cause phase reversal; however, if the input voltage exceeds the rails by more than 0.5V, the input ESD devices begin to conduct. The output stays at the rail during this overdrive condition. If the absolute maximum input  $V_{\rm IN}$  (700mV beyond either rail) is exceeded, externally limit the input current to  $\pm 5$ mA, as shown in Figure 21.

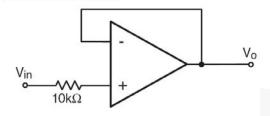


Figure 21. Circuit for Input Current Protection

### **Power Dissipation**

The maximum internal power dissipation allowed is directly related to the maximum junction temperature. If the maximum junction temperature exceeds 150°C, performance degradation occurs. If the maximum junction temperature exceeds 150°C for an extended time, device failure may occur.

### **Overdrive Recovery**

Overdrive of an amplifier occurs when the output and/or input ranges are exceeded. The recovery time varies based on whether the input or output is overdriven and by how much the range is exceeded. The FAN4931 typically recovers in less than 500ns from an overdrive condition. Figure 22 shows the FAN4931 amplifier in an overdriven condition.

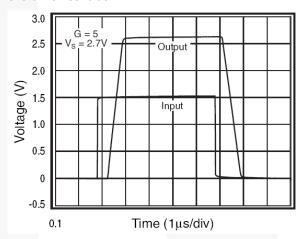


Figure 22. Overdrive Recovery

### **Driving Capacitive Loads**

Figure 8 illustrates the response of the amplifier. A small series resistance ( $R_{\rm S}$ ) at the output, illustrated in Figure 23, improves stability and settling performance.  $R_{\rm S}$  values in Figure 8 were chosen to achieve maximum bandwidth with less than 2dB of peaking. For maximum flatness, use a larger  $R_{\rm S}$ . Capacitive loads larger than 500pF require the use of  $R_{\rm S}$ .

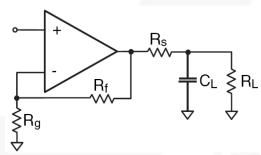


Figure 23. Typical Topology for Driving a Capacitive Load

Driving a capacitive load introduces phase-lag into the output signal, which reduces phase margin in the amplifier. The unity gain follower is the most sensitive configuration. In a unity gain follower configuration, the amplifier requires a  $300\Omega$ -series resistor to drive a 100pF load.

### **Layout Considerations**

General layout and supply bypassing play major roles in high-frequency performance. Fairchild evaluation boards help guide high-frequency layout and aid in device testing and characterization. Follow the steps below as a basis for high-frequency layout:

- 1. Include  $6.8\mu F$  and  $0.01\mu F$  ceramic capacitors.
- Place the 6.8µF capacitor within 0.75 inches of the power pin.
- Place the 0.01µF capacitor within 0.1 inches of the power pin.
- 4. Remove the ground plane under and around the part, especially near the input and output pins, to reduce parasitic capacitance.

Minimize all trace lengths to reduce series inductances.

Refer to the evaluation board layouts shown in Figures 24-26 for more information.

When evaluating only one channel, complete the following on the unused channel:

- 1. Ground the non-inverting input.
- 2. Short the output to the inverting input.

### **Evaluation Board Information**

The following evaluation board is available to aid in the testing and layout of this device.

Evaluation Board	Description	Products
FAN4931-011	Single-Channel, Dual-Supply, 5 -Lead SC70	FAN4931IP5X

Evaluation board schematics are shown in Figure 24; layouts are shown in Figures 25-26.

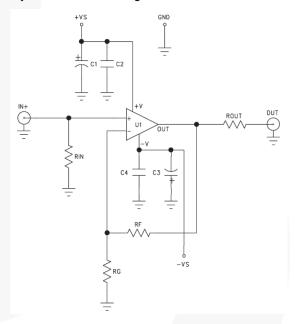


Figure 24. Evaluation Board Schematic

# **Board Layout Information**

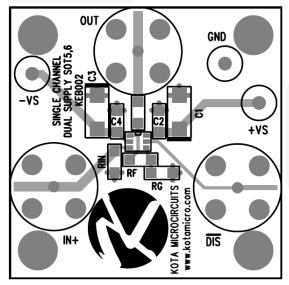


Figure 25. Top Side

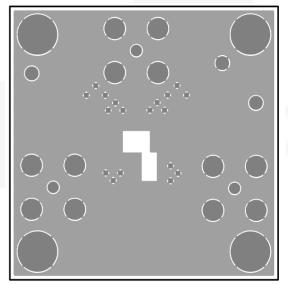


Figure 26. Bottom Side

# **Physical Dimensions SYMM** 2.00±0.20-0.65 -0.50 MIN 1.25±0.10 1.90 (0.25)-0.40 MIN 1.30 → 0.10 M A B 0.65 LAND PATTERN RECOMMENDATION 1.30 SEE DETAIL A 1.00 1.10 0.80 0.10 0.10 C -(0.43)**SEATING** 2.10±0.30 **PLANE GAGE** PLANE NOTES: UNLESS OTHERWISE SPECIFIED (R0.10) THIS PACKAGE CONFORMS TO EIAJ SC-88A, 1996. 0.25 ALL DIMENSIONS ARE IN MILLIMETERS. DIMENSIONS DO NOT INCLUDE BURRS OR MOLD FLASH. 0.20 30° DETAIL A SCALE: 2X

Figure 27. 5-Lead SC70 Package

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SuperMOS™
SyncFET™
Sync-Lock™

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GENERAL
The Power Franchise \*
the

franchiss
TinyBoost™
TinyBoost™
TinyCalc™
TinyLogic®
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#### Definition of Terms

Jermuon of Terms				
Datasheet Identification   Product Status		Definition		
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
Preliminary	First Production	Data sheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.		
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.		

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